imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

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Power MOSFET for 1-Cell Lithium-ion Battery Protection 12V, 3.2mΩ, 27A, Dual N-Channel

ON

ON Semiconductor®

www.onsemi.com

This Power MOSFET features a low on-state resistance. This device is suitable for applications such as power switches of portable machines. Best suited for 1-cell lithium-ion battery applications.

Features

- 2.5V drive
- 2kV ESD HBM
- Common-Drain Type
- ESD Diode-Protected Gate
- Pb-Free, Halogen Free and RoHS compliance

Applications

• 1-Cell Lithium-ion Battery Charging and Discharging Switch

SPECIFICATIONS

ABSOLUTE MAXIMUM RATINGS at Ta = 25°C (Note 1)

Parameter	Symbol	Value	Unit
Source to Source Voltage	VSSS	12	V
Gate to Source Voltage	VGSS	±8	V
Source Current (DC)	IS	27	А
Source Current (Pulse) PW≤100µs, duty cycle≤1%	ISP	100	А
Total Dissipation Surface mounted on ceramic substrate (5000mm ² × 0.8mm)	PT	2.5	W
Junction Temperature	Tj	150	°C
Storage Temperature	Tstg	–55 to +150	°C

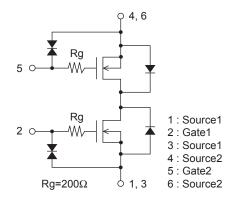
Note 1 : Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL RESISTANCE RATINGS

Parameter	Symbol	Value	Unit
Junction to Ambient Surface mounted on ceramic substrate $(5000 \text{mm}^2 \times 0.8 \text{mm})$	$R_{\theta JA}$	50	°C/W

VSSS	R _{SS} (on) Max	IS Max
	3.2mΩ@ 4.5V	
12V	3.2mΩ@ 4.0V	
	3.2mΩ@ 3.8V	27A
	4.4mΩ@ 3.1V	
	6.3mΩ@ 2.5V	

ELECTRICAL CONNECTION N-Channel





CSP6, 1.77x3.54 / EFCP3517-6DGH-020

MARKING



ORDERING INFORMATION See detailed ordering and shipping

information on page 6 of this data sheet.

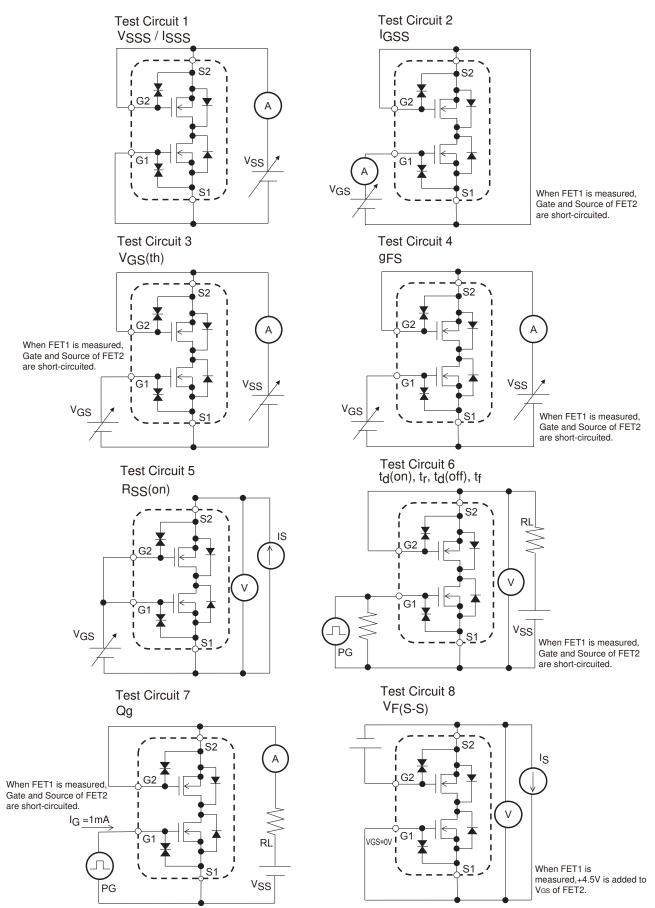
March 2016 - Rev. 0

ELECTRICAL CHARACTERISTICS at $Ta = 25^{\circ}C$ (Note 2)

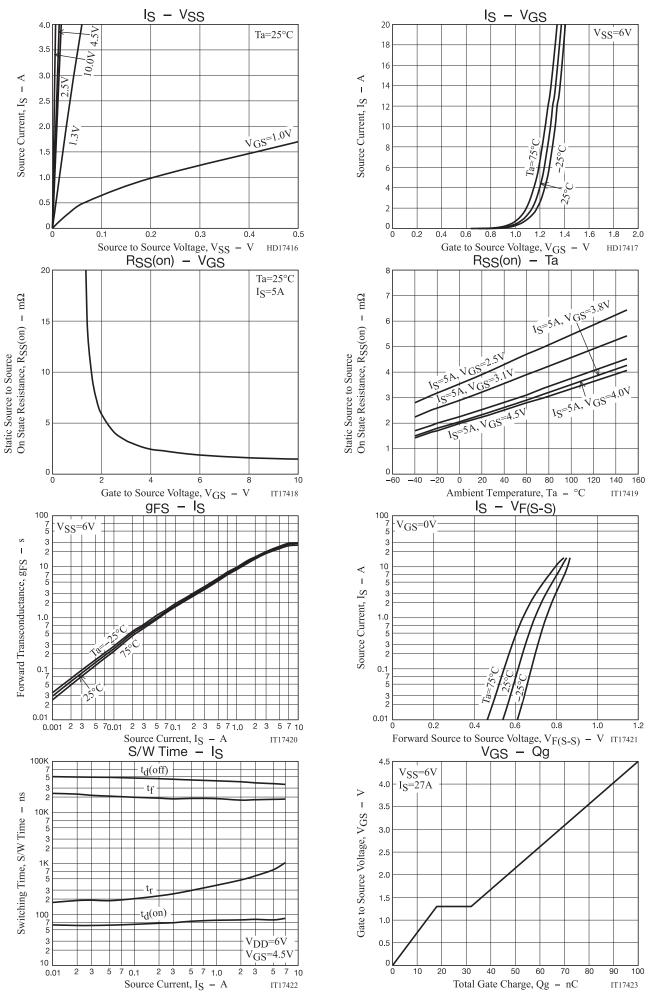
Demonster	Sumbal Conditions			Value			
Parameter	Symbol	Conditions		min	typ	max	Unit
Source to Source Breakdown Voltage	V(BR)SSS	IS=1mA, VGS=0V	Test Circuit 1	12			V
Zero-Gate Voltage Source Current	ISSS	VSS=10V, VGS=0V	Test Circuit 1			1	μA
Gate to Source Leakage Current	IGSS	VGS=±8V, VSS=0V	Test Circuit 2			±1	μA
Gate Threshold Voltage	VGS(th)	VSS=6V, IS=1mA	Test Circuit 3	0.5		1.3	V
Forward Transconductance	9FS	VSS=6V, IS=3A	Test Circuit 4		19		S
Static Source to Source On-State Resistance	RSS(on)1	IS=5A, VGS=4.5V	Test Circuit 5	1.8	2.3	3.2	mΩ
	RSS(on)2	IS=5A, VGS=4.0V	Test Circuit 5	1.9	2.4	3.2	mΩ
	RSS(on)3	IS=5A, VGS=3.8V	Test Circuit 5	2.0	2.6	3.2	mΩ
	RSS(on)4	IS=5A, VGS=3.1V	Test Circuit 5	2.1	3.3	4.4	mΩ
	RSS(on)5	IS=5A, VGS=2.5V	Test Circuit 5	2.7	4.0	6.3	mΩ
Turn-ON Delay Time	t _d (on)				80		ns
Rise Time	tr				570		ns
Turn-OFF Delay Time	t _d (off)	VSS=6V, VGS=4.5V, IS=3A Test Circuit			38,000		ns
Fall Time	tf				17,700		ns
Total Gate Charge	Qg	VSS=6V, VGS=4.5V, IS=27A	Test Circuit 7		100		nC
Forward Source to Source Voltage	VF(S-S)	IS=3A, VGS=0V	Test Circuit 8		0.75	1.2	V

Note 2 : Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

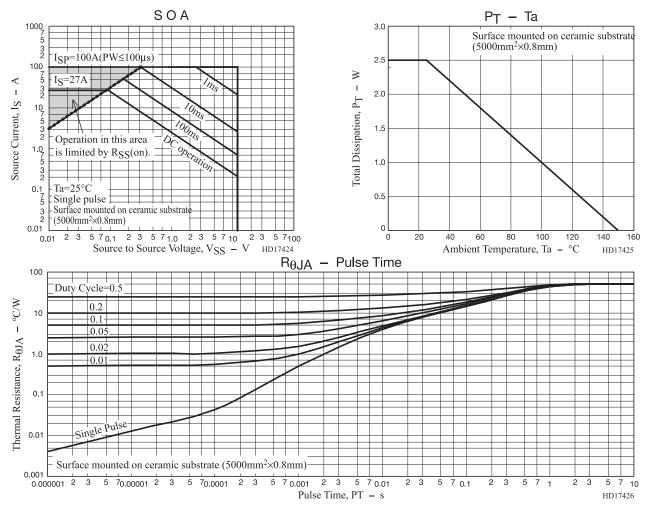
Test circuits are example of measuring FET1 side



When FET2 is measured, the position of FET1 and FET2 is switched.



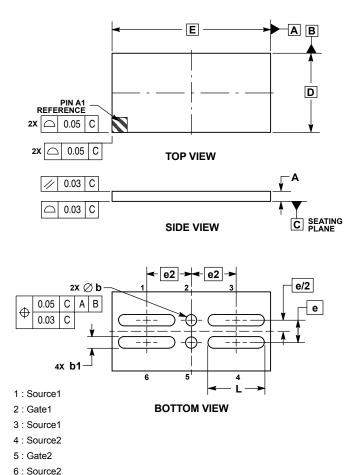
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PACKAGE DIMENSIONS unit : mm

CSP6, 1.77x3.54 / EFCP3517-6DGH-020 CASE 568AL

ISSUE O

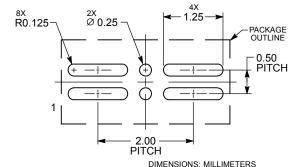


NOTES: 1. DIMENSIONING AND TOLERANCING PER ASME X14 5M 1994

ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: MILLIMETERS.

	MILLIMETERS		
DIM	MIN	MAX	
Α		0.22	
b	0.22	0.28	
b1	0.22	0.28	
D	1.77 BSC		
E	3.54 BSC		
е	0.50 BSC		
e2	1.00 BSC		
L	1.22	1.28	

RECOMMENDED SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ORDERING INFORMATION

Device	Marking	Package	Shipping (Qty / Packing)
EFC8811R-TF	ML	CSP6, 1.77x3.54 / EFCP3517-6DGH-020 (Pb-Free / Halogen Free)	5,000 / Tape & Reel

+ For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D. http://www.onsemi.com/pub_link/Collateral/BRD8011-D.PDF

Note on usage : Since the EFC8811R is a MOSFET product, please avoid using this device in the vicinity of highly charged objects. Please contact sales for use except the designated application.

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